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- Qualified for Automotive Applications
- Customer-Specific Configuration Control Can Be Supported Along With Major-Change Approval
- High Slew Rate . . . 10.5 V/μs Typ
- High-Gain Bandwidth . . . 5.1 MHz Typ
- Supply Voltage Range 2.5 V to 5.5 V

- Rail-to-Rail Output
- 360 μV Input Offset Voltage
- Low Distortion Driving 600-Ω
   0.005% THD+N
- 1 mA Supply Current (Per Channel)
- 17 nV/√Hz Input Noise Voltage
- 2 pA Input Bias Current
- Characterized From T<sub>A</sub> = −55°C to 125°C
- Available in MSOP and SOT-23 Packages
- Micropower Shutdown Mode . . . I<sub>DD</sub> < 1 μA</li>

#### description

The TLV277x CMOS operational amplifier family combines high slew rate and bandwidth, rail-to-rail output swing, high output drive, and excellent dc-precision. The device provides 10.5 V/ $\mu$ s of slew rate and 5.1 MHz of bandwidth while only consuming 1 mA of supply current per channel. This ac-performance is much higher than current competitive CMOS amplifiers. The rail-to-rail output swing and high output drive make these devices a good choice for driving the analog input or reference of analog-to-digital converters. These devices also have low distortion while driving a 600- $\Omega$  load for use in telecom systems.

These amplifiers have a  $360-\mu V$  input offset voltage, a 17 nV/ $\sqrt{\text{Hz}}$  input noise voltage, and a 2-pA input bias current for measurement, medical, and industrial applications. The TLV277x family is also specified across an extended temperature range ( $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ), making it useful for automotive systems.

These devices operate from a 2.5-V to 5.5-V single supply voltage and are characterized at 2.7 V and 5 V. The single-supply operation and low power consumption make these devices a good solution for portable applications. The following table lists the packages available.

#### **FAMILY PACKAGE TABLE**

DEVIOE	NUMBER	PAG	CKAGE T	/PES	OLULTDOWN.	UNIVERSAL
DEVICE	OF CHANNELS	SOIC	TSSOP	SOT-23	SHUTDOWN	EVM BOARD
TLV2770	1	8	_	_	Yes	
TLV2771	1	8	_	5	_	
TLV2772	2	8	8	_	_	See the EVM
TLV2773	2	14	_	_	Yes	Selection Guide (SLOU060)
TLV2774	4	14	14	_	_	, , , , , , , , , , , , , , , , , , , ,
TLV2775	4	16	16	_	Yes	



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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#### A SELECTION OF SINGLE-SUPPLY OPERATIONAL AMPLIFIER PRODUCTS<sup>†</sup>

DEVICE	V <sub>DD</sub> (V)	BW (MHz)	SLEW RATE (V/μs)	I <sub>DD</sub> (per channel) (μA)	RAIL-TO-RAIL
TLV277X	2.5 – 6	5.1	10.5 1000		0
TLV247X	2.7 – 6	2.8	1.5	600	I/O
TLV245X	2.7 – 6	0.22	0.11	23	I/O
TLV246X	2.7 – 6	6.4	1.6	550	I/O

<sup>†</sup> All specifications measured at 5 V.

#### **ORDERING INFORMATION**

TA	V <sub>IO</sub> max AT 25°C (mV)	PACKAGE <sup>‡</sup> ORDERABLE PART NUMBER		_	TOP-SIDE MARKING
4000 1- 40500	2.5	SOIC (D)	Tape and reel	TLV2770QDRQ1§	
-40°C to 125°C	1.6	SOIC (D)	Tape and reel	TLV2770AQDRQ1§	
	2.5	SOT-23	Tape and reel	TLV2771QDBVRQ1	VBPQ
-40°C to 125°C	2.5	SOIC (D)	Tape and reel	TLV2771QDRQ1§	
	1.6	SOIC (D)	Tape and reel	TLV2771AQDRQ1§	
	0.5	SOIC (D)	Tape and reel	TLV2772QDRQ1	TLV2772QI
4000 / 40500	2.5	TSSOP (PW)	Tape and reel	TLV2772QPWRQ1	TLV2772QI
–40°C to 125°C	1.6	SOIC (D)	Tape and reel	TLV2772AQDRQ1	TLV2772AQ
		TSSOP (PW)	Tape and reel	TLV2772AQPWRQ1	TLV2772AQ
1000 / 10500	2.5	SOIC (D)	Tape and reel	TLV2773QDRQ1§	
-40°C to 125°C	1.6	SOIC (D)	Tape and reel	TLV2773AQDRQ1§	
	0.7	SOIC (D)	Tape and reel	TLV2774QDRQ1§	
4000 1- 40500	2.7	TSSOP (PW)	Tape and reel	TLV2774QPWRQ1§	
–40°C to 125°C	0.4	SOIC (D)	Tape and reel	TLV2774AQDRQ1§	
	2.1	TSSOP (PW)	Tape and reel	TLV2774AQPWRQ1§	
	0.7	SOIC (D)	Tape and reel	TLV2775QDRQ1§	
	2.7	TSSOP (PW)	Tape and reel	TLV2775QPWRQ1§	
-40°C to 125°C	0.4	SOIC (D)	Tape and reel	TLV2775AQDRQ1§	
	2.1	TSSOP (PW)	Tape and reel	TLV2775AQPWRQ1§	

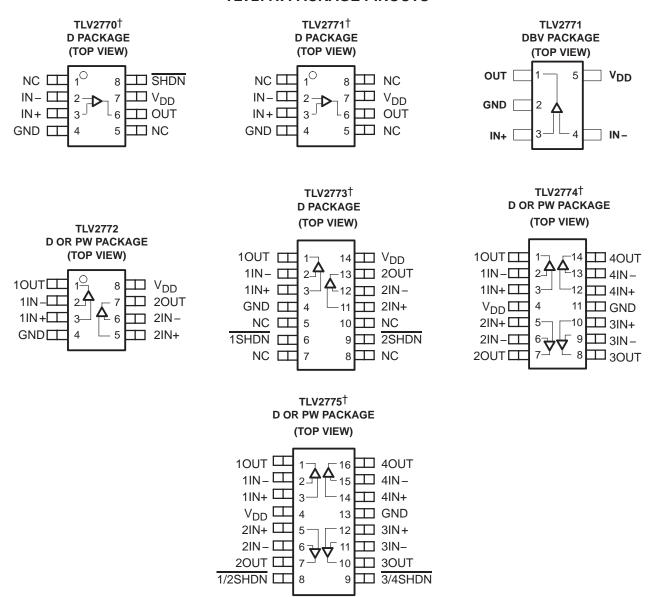
<sup>&</sup>lt;sup>‡</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



<sup>§</sup> Product Preview

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#### **TLV277x PACKAGE PINOUTS**



NC - No internal connection

† This device is in the Product Preview stage of development. Contact your local Texas Instruments sales office for availability.

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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V <sub>DD</sub> (see Note 1)	
Differential input voltage, V <sub>ID</sub> (see Note 2)	±V <sub>DD</sub>
Input voltage range, V <sub>I</sub> (any input, see Note 1)	–0.3 V to V <sub>DD</sub>
Input current, I <sub>I</sub> (any input)	±4 mA
Output current, IO	±50 mA
Total current into V <sub>DD+</sub>	±50 mA
Total current out of GND	±50 mA
Duration of short-circuit current (at or below) 25°C (see Note 3)	unlimited
Continuous total power dissipation	. See Dissipation Rating Table
Operating free-air temperature range, T <sub>A</sub> : Q suffix	–40°C to 125°C
Storage temperature range, T <sub>stq</sub>	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to GND.
  - 2. Differential voltages are at the noninverting input with respect to the inverting input. Excessive current flows when input is brought below GND 0.3 V.
  - 3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

#### **ESD RATING TABLE**

	Human Body Model	2 (H1C)	kV
ESD rating <sup>(4)</sup>	Charged-Device Model	1 (C5)	KV
	Machine Model	150 (M2)	V

NOTE 4: ESD protection level per AEC Q100 Classification TLV2771QDBVRQ1

#### **DISSIPATION RATING TABLE**

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING	T <sub>A</sub> = 125°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW
DBV	437 mW	3.5 mW/°C	280 mW	227 mW	87 mW
PW	700 mW	5.6 mW/°C	448 mW	364 mW	140 mW

#### recommended operating conditions

	MIN I 2.5 GND VD GND VD	SUFFIX	
	MIN	MAX	UNIT
Supply voltage, V <sub>DD</sub>	2.5	6	V
Input voltage range, V <sub>I</sub>	GND	V <sub>DD+</sub> -1.3	V
Common-mode input voltage, V <sub>IC</sub>	GND	V <sub>DD+</sub> -1.3	V
Operating free-air temperature, T <sub>A</sub>	-40	125	°C



# TLV277x-Q1, TLV277xA-Q1 FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN SGLS179B- SEPTEMBER 2003 - REVISED APRIL 2006

## electrical characteristics at specified free-air temperature, $V_{DD}$ = 2.7 V (unless otherwise noted)

	DADAMETED	TEST COMPITIONS	T - +	TL	V2771-0	21		
	PARAMETER	TEST CONDITIONS	T <sub>A</sub> †	MIN	TYP	MAX	UNIT	
V	lanut offeet voltage	$V_{IC} = 0, V_{O} = 0, R_{S} = 50 \Omega$	25°C		0.48	2.5	m)/	
V <sub>IO</sub>	Input offset voltage	$V_{DD} = \pm 1.35 \text{ V}$ , No load	Full range		0.53	2.7	mV	
αΝΙΟ	Temperature coefficient of input offset voltage		25°C to 125°C		2		μV/°C	
		T., .,	25°C		1	60		
lio	Input offset current	$V_{IC} = 0, V_{O} = 0, R_{S} = 50 \Omega$	Full range		2	125	рA	
	lament bing assument		25°C		2	60	- ^	
IB	Input bias current		Full range	6 3		350	pА	
		0.0754	25°C		2.6			
\/ - · ·	High lovel output voltage	$I_{OH} = -0.675 \text{ mA}$	Full range		2.5		,,	
VOH	High-level output voltage		25°C		2.4		V	
		I <sub>OH</sub> = -2.2 mA	Full range		2.1			
		V 4.05 V 1 0.075 ··· A	25°C		0.1			
V	L Low-level output voltage	$V_{IC} = 1.35 \text{ V}, I_{OL} = 0.675 \text{ mA}$	Full range		0.2		V	
VOL		, ,			0.21		V	
		$V_{IC} = 1.35 \text{ V}, I_{OL} = 2.2 \text{ mA}$	Full range		0.6			
۸	Large-signal differential voltage	$V_{IC} = 1.35 \text{ V}, R_L = 10 \text{ k}\Omega^{\ddagger},$	25°C	20	380		1//201/	
AVD	amplification	$V_0 = 0.6 \text{ V to } 2.1 \text{ V}$	Full range	13			V/IIIV	
ri(d)	Differential input resistance		25°C		1012		Ω	
Ci(c)	Common-mode input capacitance	f = 10 kHz	25°C		8		pF	
z <sub>O</sub>	Closed-loop output impedance	$f = 100 \text{ kHz}, A_V = 10$	25°C		25		Ω	
CMRR	Common mode rejection ratio	$V_{IC} = 0$ to 1.5 V, $V_{O} = V_{DD}/2$ ,	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	٩D				
CIVIKK	Common-mode rejection ratio	$R_S = 50 \Omega$	Full range	60	82		uБ	
kove	Supply voltage rejection ratio	$V_{DD} = 2.7 \text{ V to 5 V}, V_{IC} = V_{DD}/2,$	25°C	70	89		dB	
ksvr	(ΔV <sub>DD</sub> /ΔV <sub>IO</sub> )	No load	Full range	70	84		UБ	
lDD	Supply current (per channel)	V <sub>O</sub> = V <sub>DD</sub> /2, No load	25°C		1	2	mA	
טטי	oupply culterit (per chaille)	VO - VDD/2, NO load	Full range			2 2	m/A	

<sup>†</sup> Full range is – 40°C to 125°C for Q level part. ‡ Referenced to 1.35 V

# TLV277x-Q1, TLV277xA-Q1 FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT **OPERATIONAL AMPLIFIERS WITH SHUTDOWN** SGLS179B- SEPTEMBER 2003 - REVISED APRIL 2006

## operating characteristics at specified free-air temperature, $V_{DD}$ = 2.7 V (unless otherwise noted)

	242445752	TEST COMPLETION	TEGT CONDITIONS		TL	LIMIT		
	PARAMETER	TEST CONDITION	TEST CONDITIONS         TA <sup>†</sup> MIN           25°C         5           Full range         4.7           ε 1 kHz         25°C           ε 10 kHz         25°C           ε 0.1 Hz to 1 Hz         25°C           ε 0.1 Hz to 10 Hz         25°C           ε 100 Hz         25°C           ε 100 Hz         25°C           ε 100 Hz         25°C           ε 100 Hz         25°C           ε 10 kHz, RL = 600 Ω, CL = 100 pF         25°C           ε 10 kHz, RL = 600 Ω, CL = 100 pF         25°C           ε 10 kHz, RL = 600 Ω, CL = 100 pF         25°C	TYP	MAX	UNIT		
0.0	Olements of multiplication	V 0.0.V.O 400E	D 4010	25°C	5	9		\// -
SR	Slew rate at unity gain	VO(PP) = 0.8  V, CL = 100  pr,	KL = 10 KΩ	Full range	4.7	6		V/μs
.,	Emiliate the standard and a subtract	f = 1 kHz		25°C		5 9		->/// <del> </del>   -
V <sub>n</sub>	Equivalent input noise voltage	f = 10 kHz		25°C		17		nV/√Hz
,,	Peak-to-peak equivalent input	f = 0.1 Hz to 1 Hz		25°C	0.33			μV
V <sub>N(PP)</sub>	noise voltage	f = 0.1 Hz to 10 Hz		25°C	0.86			μV
In	Equivalent input noise current	f = 100 Hz		25°C		0.6		fA/√Hz
'11			A <sub>V</sub> = 1		C	.0085%		
THD + N	Total harmonic distortion plus noise	$R_L = 600 \Omega$ , $f = 1 \text{ kHz}$	$A_{V} = 10$	25°C		0.025%		
	110130		$A_{V} = 100$		0.12%			
	Gain-bandwidth product	$f = 10 \text{ kHz}, R_L = 600 \Omega, C_L = 600 \Omega$	= 100 pF	25°C		4.8		MHz
	0 111 11	$A_V = -1$ ,	0.1%	25°C		0.186		
t <sub>S</sub>	Settling time	Step = 0.85 V to 1.85 V, $R_L = 600 \Omega$ , $C_L = 100 pF$	0.01%	25°C		3.92		μs
φm	Phase margin at unity gain	D. 000 O C. 400 - E				46°		
	Gain margin	$R_L = 600 \Omega$ , $C_L = 100 pF$		25°C		12		dB

<sup>†</sup> Full range is –40°C to 125°C.



# TLV277x-Q1, TLV277xA-Q1 FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN SGLS179B- SEPTEMBER 2003 - REVISED APRIL 2006

## electrical characteristics at specified free-air temperature, $V_{DD} = 5 \text{ V}$ (unless otherwise noted)

	DADAMETED	TEST	- +	TL	V2771-0	21	
	PARAMETER	CONDITIONS	T <sub>A</sub> †	MIN	TYP	MAX	UNIT
\/	lanut offeet voltage	V <sub>IC</sub> = 0, No load	25°C		0.5	2.5	mV
VIO	Input offset voltage	$V_0 = 0$ , $R_S = 50 \Omega$ , $V_{DD} = \pm 2.5 V$	Full range		0.6	2.7	mv
αΛΙΟ	Temperature coefficient of input offset voltage	25°C to 125°C 2					
	hand effect coment	T.,	25°C		1	60	4
lio	Input offset current	$V_{IC} = 0, V_O = 0, R_S = 50 \Omega, V_{DD} = \pm 2.5 V$	Full range		2	125	рA
	lanut bigg gurrant		25°C		2	60	~ ^
IB	Input bias current		Full range		6	350	рA
		1	25°C		4.9		
V	High level output valtage	I <sub>OH</sub> = -1.3 mA	Full range		4.8		V
VOH	High-level output voltage	Jan. 4.2 mA	25°C		4.7		V
		I <sub>OH</sub> = -4.2 mA	Full range		4.4		
		V <sub>IC</sub> = 2.5 V, I <sub>OL</sub> = 1.3 mA	25°C		0.1		V
1/01	Low-level output voltage	VIC = 2.5 V, IOL = 1.5 IIIA	Full range		0.2		
VOL	Low-level output voltage	V <sub>IC</sub> = 2.5 V, I <sub>OI</sub> = 4.2 mA	25°C		0.21		
		VIC = 2.5 V, IOL = 4.2 IIIA	Full range		0.6		
۸۷۳	Large-signal differential voltage	$V_{IC} = 2.5 \text{ V}, R_{I} = 10 \text{ k}\Omega^{\ddagger}, V_{O} = 1 \text{ V to 4 V}$	25°C	20	450		V/mV
AVD	amplification	VIC = 2.5 V, INC = 10 K321, VO = 1 V 10 4 V	Full range	13			V/IIIV
r <sub>i(d)</sub>	Differential input resistance		25°C		1012		Ω
<sup>C</sup> i(c)	Common-mode input capacitance	f = 10 kHz	25°C		8		pF
z <sub>O</sub>	Closed-loop output impedance	$f = 100 \text{ kHz}, A_V = 10$	25°C		20		Ω
CMRR	Common mode rejection ratio	$V_{IC} = 0 \text{ to } 3.7 \text{ V},$	25°C	60	96		чD
CIVIKK	Common-mode rejection ratio	$V_O = V_{DD}/2$ , $R_S = 50 \Omega$	Full range	60	93		dB
kovr	Supply voltage rejection ratio	$V_{DD} = 2.7 \text{ V to 5 V},$	25°C	70	89		dB
ksvr	(ΔV <sub>DD</sub> /ΔV <sub>IO</sub> )	V <sub>IC</sub> = V <sub>DD</sub> /2, No load	Full range	70	84		UD
IDD	Supply current (per channel)	V <sub>O</sub> = V <sub>DD</sub> /2, No load	25°C		1	2	mA
יטט.	capply current (per charmer)	VO — VDD/2, No load	Full range			2	IIIA

<sup>†</sup> Full range is – 40°C to 125°C for Q level part. ‡ Referenced to 2.5 V

# TLV277x-Q1, TLV277xA-Q1 FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT **OPERATIONAL AMPLIFIERS WITH SHUTDOWN** SGLS179B- SEPTEMBER 2003 - REVISED APRIL 2006

## operating characteristics at specified free-air temperature, $V_{DD} = 5 \text{ V}$ (unless otherwise noted)

					TL	V2771-Q1		
	PARAMETER	TEST CONDITIO	ONS	T <sub>A</sub> †	MIN	TYP	MAX	UNIT
0.0	01			25°C	5	10.5		.,,
SR	Slew rate at unity gain	VO(PP) = 1.5  V,  CL = 100  J	$V_{O(PP)} = 1.5 \text{ V, } C_{L} = 100 \text{ pF, } R_{L} = 10 \text{ k}\Omega$		4.7	6		V/μs
.,		f = 1 kHz		25°C	17		\(\lambda \in \frac{1}{1}	
V <sub>n</sub>	Equivalent input noise voltage	f = 10 kHz		25°C		12		nV/√Hz
. ,	Peak-to-peak equivalent input f = 0.1 Hz to 1	f = 0.1 Hz to 1 Hz		25°C	0.33			μV
V <sub>N(PP)</sub>	noise voltage	f = 0.1 Hz to 10 Hz		25°C	0.86			μV
In	Equivalent input noise current	f = 100 Hz		25°C	0.6			fA/√Hz
		_	A <sub>V</sub> = 1		0.005%			
THD + N	Total harmonic distortion plus noise	$R_L = 600 \Omega$ , $f = 1 \text{ kHz}$	A <sub>V</sub> = 10	25°C	0.016% 0.095%			
	110136	I - I KIIZ	A <sub>V</sub> = 100					
	Gain-bandwidth product	f = 10 kHz, R <sub>L</sub> = 600 Ω, C <sub>L</sub>	= 100 pF	25°C		5.1		MHz
	0	$A_V = -1$ ,	0.1%	25°C		0.134		
t <sub>S</sub>	Settling time	Step = 1.5 V to 3.5 V, $R_L = 600 \Omega$ , $C_L = 100 pF$	0.01%	25°C	25°C 1.97			μS
φm	Phase margin at unity gain	D 000 0 0 400 "F	R <sub>L</sub> = 600 Ω, C <sub>L</sub> = 100 pF			46°		
	Gain margin	$RL = 600 \Omega, CL = 100 \text{ pF}$				12		dB

<sup>†</sup> Full range is –40°C to 125°C.



# TLV277x-Q1, TLV277xA-Q1 FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN SGLS179B- SEPTEMBER 2003 - REVISED APRIL 2006

# electrical characteristics at specified free-air temperature, $V_{DD}$ = 2.7 V (unless otherwise noted)

	PARAMETER	TEST CONI	OITIONS	T <sub>A</sub> †	TL	V2772-0	<b>Q</b> 1	TLV	2772A-	Q1	
	PARAMETER	TEST CONI	DITIONS	'A'	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
VIO	Input offset voltage			25°C		0.44	2.5		0.44	1.6	mV
VIO	input onset voltage			Full range		0.47	2.7		0.47	1.9	IIIV
αVIO	Temperature coefficient of input offset voltage	$V_{DD} = \pm 1.35 \text{ V},$ $V_{IC} = 0,$	$V_{O} = 0$ ,	25°C to 125°C		2			2		μV/°C
		$R_S = 50 \Omega$		25°C		1	60		1	60	
liO	Input offset current			Full range		2	125		2	125	pΑ
l	Innut bigg gurrant	]		25°C		2	60		2	60	n 1
lΒ	Input bias current			Full range		6	350		6	350	рA
VICR	Common-mode input voltage range	CMRR > 60 dB,	R <sub>S</sub> = 50 Ω	25°C	0 to 1.4	-0.3 to 1.7		0 to 1.4	-0.3 to 1.7		٧
	mpat romago rango			Full range	to 1.4	to 1.7		to 1.4	to 1.7		
		1 0.67F mA		25°C		2.6			2.6		V
Vall	High-level output	$I_{OH} = -0.675 \text{ mA}$		Full range	2.45			2.45			
VOH	voltage	I <sub>OH</sub> = -2.2 mA		25°C		2.4			2.4		
		IOH = -2.2 IIIA		Full range	2.1			2.1			
	V	Low-level output voltage $ V_{IC} = 1.35 \text{ V}, \qquad I_{OL} = 0.675 \text{ mA} $ $ V_{IC} = 1.35 \text{ V}, \qquad I_{OL} = 2.2 \text{ mA} $	lou = 0.675 mA	25°C		0.1			0.1		
VOL	Low-level output		Full range			0.2			0.2	- <sub>V</sub>	
VOL	voltage		I <sub>OL</sub> = 2.2 mA	25°C		0.21			0.21		•
				Full range			0.6			0.6	
$A_{VD}$	Large-signal differential voltage	$V_{IC} = 1.35 \text{ V},$ $V_{O} = 0.6 \text{ V to } 2.1 \text{ V}$	$R_L = 10 \text{ k}\Omega,^{\ddagger}$	25°C Full range	20 13	380		20 13	380		V/mV
r <sub>i(d)</sub>	amplification  Differential input resistance			25°C	10	10 <sup>12</sup>		10	1012		Ω
<sup>C</sup> i(c)	Common-mode input capacitance	f = 10 kHz,		25°C		8			8		pF
z <sub>O</sub>	Closed-loop output impedance	f = 100 kHz,	A <sub>V</sub> = 10	25°C		25			25		Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}$ (min), R <sub>S</sub> = 50 $\Omega$	$V_{O} = 1.5 V,$	25°C Full range	60 60	84 82		60 60	84 82		dB
ksvr	Supply voltage rejection ratio	V <sub>DD</sub> = 2.7 V to 5 V,	$V_{IC} = V_{DD}/2$ ,	25°C	70	89		70	89		dB
341	(ΔV <sub>DD</sub> /ΔV <sub>IO</sub> )	No load		Full range	70	84		70	84		
I <sub>DD</sub>	Supply current	V <sub>O</sub> = 1.5 V,	No load	25°C		1	2		1	2	mA
טטי	(per channel)	V 0 = 1.5 v,	140 1000	Full range			2			2	111/

<sup>†</sup> Full range is –40°C to 125°C for Q level part. ‡ Referenced to 1.35 V



# TLV277x-Q1, TLV277xA-Q1 FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN SGLS179B- SEPTEMBER 2003 - REVISED APRIL 2006

# operating characteristics at specified free-air temperature, $V_{DD}$ = 2.7 V (unless otherwise noted)

		TEOT 001		_ +	TL	TLV2772-Q1 TLV			TLV2772A-Q1			
PARAMETER		TEST CONI	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	UNIT		
			0 400 ·· F	25°C	5	9		5	9			
SR	Slew rate at unity gain	$V_{O(PP)} = 0.8 \text{ V},$ $R_{L} = 10 \text{ k}\Omega$	CL = 100 pF,	Full range	4.7	6		4.7	6		V/μs	
.,	Equivalent input	f = 1 kHz		25°C		21			21		->/// <del>  -</del>	
Vn	noise voltage	f = 10 kHz	25°C	5°C 17 17				17		nV/√Hz		
Peak-to-peak VN(PP) equivalent input noise voltage		f = 0.1 Hz to 1 Hz		25°C		0.33		0.33		μV		
		f = 0.1 Hz to 10 Hz		25°C		0.86		0.86			μV	
In	Equivalent input noise current	f = 100 Hz	25°C	0.6		0.6			fA/√Hz			
	Total harmonic distortion plus noise		A <sub>V</sub> = 1		0.0085%			(	0.0085%			
THD + N		$R_L = 600 \Omega$ , f = 1  kHz	A <sub>V</sub> = 10	25°C		0.025%			0.025%			
		1 - 1 1012	A <sub>V</sub> = 100			0.12%			0.12%			
	Gain-bandwidth product	f = 10 kHz, C <sub>L</sub> = 100 pF	$R_L = 600 \Omega$ ,	25°C		4.8			4.8		MHz	
t <sub>S</sub>	Settling time		$A_V = -1$ , Step = 0.85 V to	0.1%	25°C		0.186			0.186		
		$1.85 \text{ V},$ $R_L = 600 \Omega,$ $C_L = 100 \text{ pF}$	0.01%	25°C		3.92			3.92		μS	
фm	Phase margin at unity gain	R <sub>L</sub> = 600 Ω,	C <sub>L</sub> = 100 pF	25°C		46°			46°	_		
	Gain margin		-	25°C		12			12		dB	

<sup>†</sup> Full range is –40°C to 125°C for Q level part.



# TLV277x-Q1, TLV277xA-Q1 FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN SGLS179B- SEPTEMBER 2003 - REVISED APRIL 2006

# electrical characteristics at specified free-air temperature, $V_{DD}$ = 5 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		T <sub>A</sub> †	TL	V2772-0	Q1	TLV2772A-Q1			UNIT	
	PARAMETER	TEST COND	IIIONS	'A'	MIN	TYP	MAX	MIN	TYP	MAX	UNII	
V <sub>IO</sub>	Input offset voltage			25°C		0.36	2.5		0.36	1.6	mV	
۷۱0	Input ondet voltage	1		Full range		0.4	2.7		0.4	1.9	111.4	
$\alpha$ VIO	Temperature coefficient of input offset voltage	$V_{DD} = \pm 2.5 \text{ V},$	V <sub>O</sub> = 0,	25°C to 125°C		2			2		μV/°C	
	land that were	$V_{IC} = 0$ ,	$R_S = 50 \Omega$	25°C		1	60		1	60	4	
lio	Input offset current			Full range		2	125		2	125	рA	
lin	Input bias current			25°C		2	60		2	60	4	
IB	input bias current			Full range		6	350		6	350	рA	
VICR Common-mode input voltage range		CMRR > 60 dB,	Rs = 50 Ω	25°C	0 to 3.7	-0.3 to 3.8		0 to 3.7	-0.3 to 3.8		V	
	input voitage range	input voltage range		_	Full range	0 to 3.7	-0.3 to 3.8		0 to 3.7	-0.3 to 3.8		
V		12 mΛ		25°C		4.9			4.9		V	
	High-level output voltage	I <sub>OH</sub> = -1.3 mA		Full range	4.8			4.8				
VOH		I <sub>OH</sub> = -4.2 mA		25°C		4.7			4.7			
		10H = -4.2 IIIA		Full range	4.4			4.4				
		V <sub>IC</sub> = 2.5 V,	I <sub>OL</sub> = 1.3 mA	25°C		0.1			0.1		- v	
VOL	Low-level output	V <sub>1</sub> C = 2.0 V,	10[ = 1.0 11.7	Full range			0.2			0.2		
·OL	voltage	V <sub>IC</sub> = 2.5 V,	I <sub>OL</sub> = 4.2 mA	25°C		0.21			0.21			
		10 - ,		Full range			0.6			0.6		
۸۰۰۰	Large-signal differential voltage	V <sub>IC</sub> = 2.5 V,	$R_L = 10 \text{ k}\Omega,^{\ddagger}$	25°C	20	450		20	450		\//>/	
$A_{VD}$	amplification	$V_O = 1 \text{ V to 4 V}$		Full range	13			13			V/mV	
ri(d)	Differential input resistance			25°C		1012			1012		Ω	
c <sub>i(c)</sub>	Common-mode input capacitance	f = 10 kHz,		25°C		8			8		pF	
z <sub>O</sub>	Closed-loop output impedance	f = 100 kHz,	A <sub>V</sub> = 10	25°C		20			20		Ω	
CMDD	Common-mode	V <sub>IC</sub> = V <sub>ICR</sub> (min),	$V_0 = 3.7 V$	25°C	60	96		60	96		dB	
CIVINN	CMRR rejection ratio $R_S = 50 \Omega$				60	93		60	93		uБ	
ksvr	Supply voltage rejection ratio	$V_{DD} = 2.7 \text{ V to 5 V},$ No load	$V_{IC} = V_{DD}/2$ ,	25°C	70	89		70	89		dB	
	(ΔV <sub>DD</sub> /ΔV <sub>IO</sub> )	140 load		Full range	70	84		70	84			
IDD	Supply current	V <sub>O</sub> = 1.5 V,	No load	25°C		1	2		1	2	mA	
טטי	(per channel)			Full range			2			2	111/4	

<sup>†</sup> Full range is –40°C to 125°C for Q level part. ‡ Referenced to 2.5 V



# TLV277x-Q1, TLV277xA-Q1 FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT **OPERATIONAL AMPLIFIERS WITH SHUTDOWN** SGLS179B- SEPTEMBER 2003 - REVISED APRIL 2006

# operating characteristics at specified free-air temperature, $V_{DD} = 5 \text{ V}$ (unless otherwise noted)

PARAMETER		TEOT 001	DITIONS	- +	TL	TLV2772-Q1		TLV	TLV2772A-Q1			
		TEST CON	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	UNIT		
		V 4.5.V	C: 400 = F	25°C	5	10.5		5	10.5			
SR	Slew rate at unity gain	$V_{O(PP)} = 1.5 \text{ V},$ $R_{L} = 10 \text{ k}\Omega$	CL = 100 pr,	Full range	4.7	6		4.7	6		V/μs	
.,	Equivalent input	f = 1 kHz f = 10 kHz		25°C		17			17		->4/ <del>  -</del>	
Vn	noise voltage			25°C		12			12		nV/√Hz	
.,	Peak-to-peak	f = 0.1 Hz to 1 Hz		25°C		0.33			0.33		μV	
V <sub>N(PP)</sub> equivalent input noise voltage		f = 0.1 Hz to 10 Hz		25°C		0.86			0.86		μV	
In	Equivalent input noise current	f = 100 Hz		25°C		0.6			0.6		fA/√ <del>Hz</del>	
	Total harmonic distortion plus noise		A <sub>V</sub> = 1			0.005%			0.005%			
THD + N		$R_L = 600 \Omega$ , $f = 1 \text{ kHz}$	A <sub>V</sub> = 10	25°C		0.016%			0.016%			
		1 - 1 Ki i 2	A <sub>V</sub> = 100			0.095%			0.095%			
	Gain-bandwidth product	f = 10 kHz, C <sub>L</sub> = 100 pF	$R_L = 600 \Omega$ ,	25°C		5.1			5.1		MHz	
t <sub>S</sub> Set	Settling time	0.00	$A_V = -1$ , Step = 1.5 V to 3.5 V.	0.1%	25°C		0.134			0.134		
		$R_L = 600 \Omega$ , $C_L = 100 pF$	0.01%	25°C		1.97			1.97		μS	
φm	Phase margin at unity gain	R <sub>L</sub> = 600 Ω,	C <sub>L</sub> = 100 pF	25°C		46°			46°			
	Gain margin			25°C		12			12		dB	

<sup>†</sup>Full range is -40°C to 125°C for Q level part.



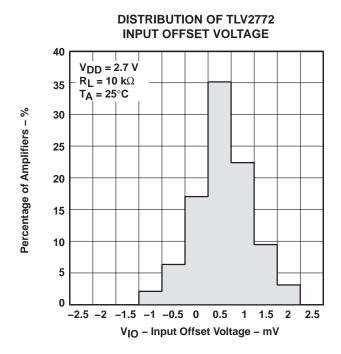
# TLV277x-Q1, TLV277xA-Q1 FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN SGLS179B- SEPTEMBER 2003 - REVISED APRIL 2006

#### **TYPICAL CHARACTERISTICS**

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**INPUT OFFSET VOLTAGE** 40  $V_{DD} = 5 V$  $R_L = 10 \text{ k}\Omega$ 35 T<sub>A</sub> = 25°C Percentage of Amplifiers - % 30 25 20 15 10 5 -2.5 -2 -1.5 -1 -0.5 0 0.5

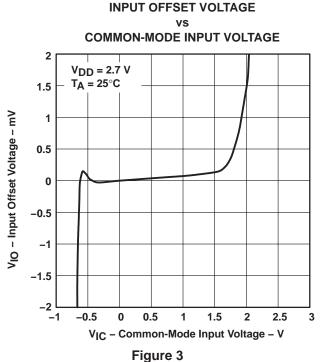
**DISTRIBUTION OF TLV2772** 

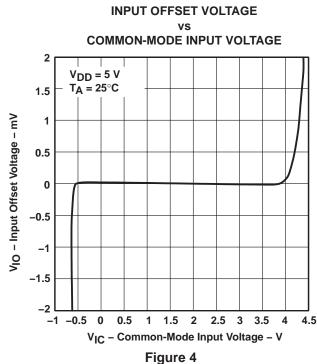
Figure 1

Figure 2

V<sub>IO</sub> - Input Offset Voltage - mV

1 1.5 2 2.5





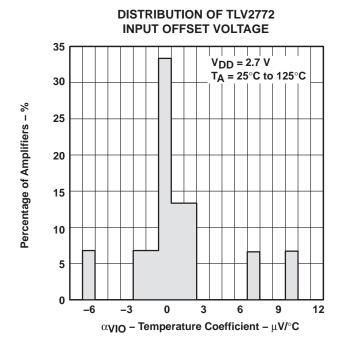
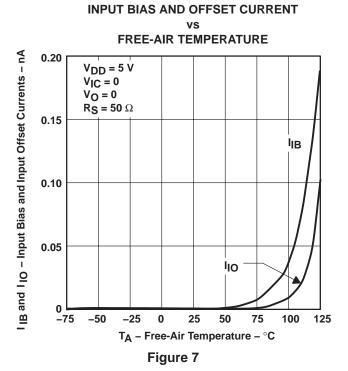


Figure 5



DISTRIBUTION OF TLV2772 INPUT OFFSET VOLTAGE

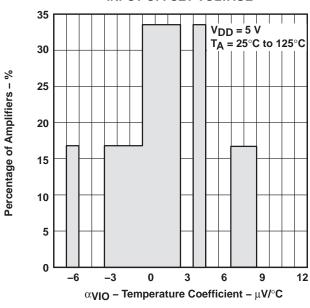
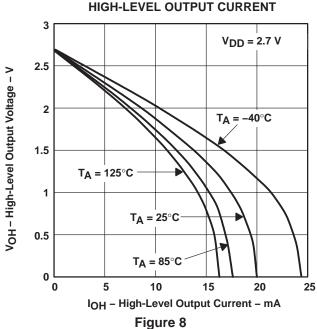
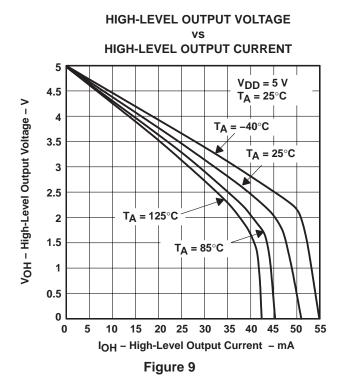


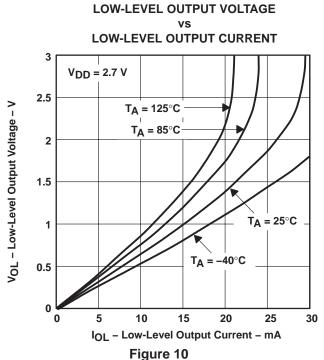
Figure 6

# HIGH-LEVEL OUTPUT VOLTAGE VS HIGH-LEVEL OUTPUT CURRENT

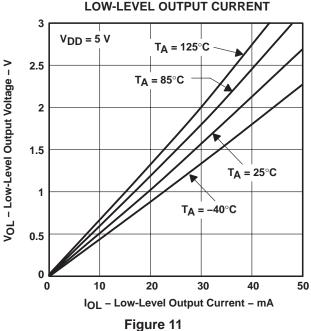


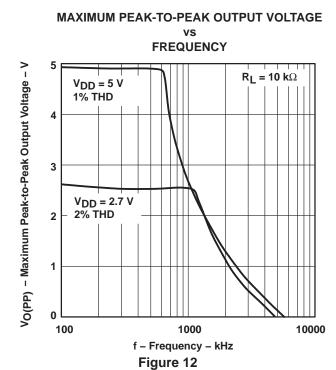
#### TYPICAL CHARACTERISTICS











## MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE

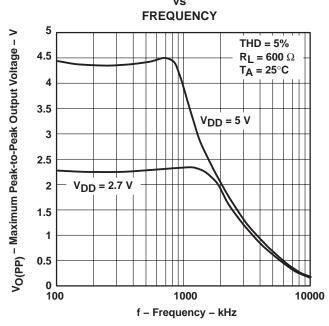


Figure 13

# SHORT-CIRCUIT OUTPUT CURRENT vs

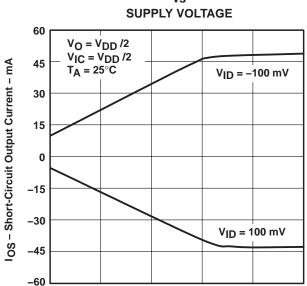


Figure 14

4

5

V<sub>DD</sub> - Supply Voltage - V

6

7

2

3

## SHORT-CIRCUIT OUTPUT CURRENT

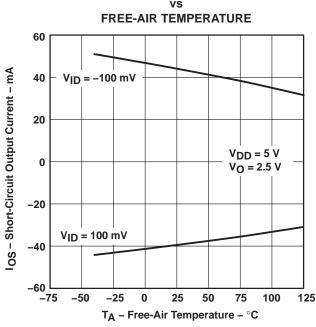


Figure 15

OUTPUT VOLTAGE vs

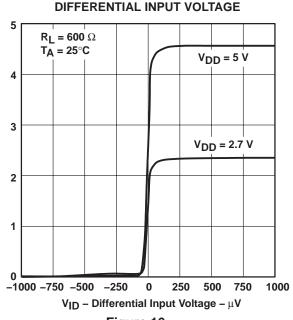


Figure 16

Vo - Output Voltage - V

# LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN

vs **FREQUENCY** 100 300 A<sub>VD</sub> - Large-Signal Differential Amplification - dB  $V_{DD} = 2.7 \text{ V}$  $R_L = 600 \Omega$  $C_{L} = 600 \text{ pF}$ 80 240 T<sub>A</sub> = 25°C  $A_{VD}$ Phase Margin – degrees 60 180 120 40 Phase 60 20 0 0 Ε -20 60 -90 -40 100 1k 10k 100k 10M f - Frequency - Hz

Figure 17

# LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE MARGIN

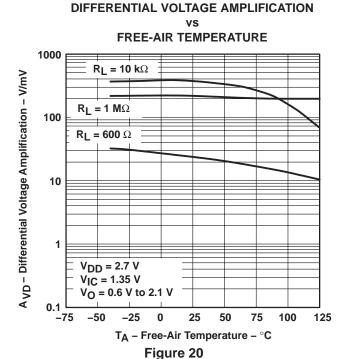
٧S **FREQUENCY** 100 300 A<sub>VD</sub> - Large-Signal Differential Amplification - dB  $V_{DD} = 5 V$  $R_L = 600 \Omega$  $C_{L}^{-} = 600 \text{ pF}$ 80 240 T<sub>A</sub> = 25°C Phase Margin – degrees AVD60 180 40 120 Phase 20 60 ī 0 0 . ₽ 0 -20 -60 -90 -40 100 1k 100k 10k 1M 10M f - Frequency - Hz

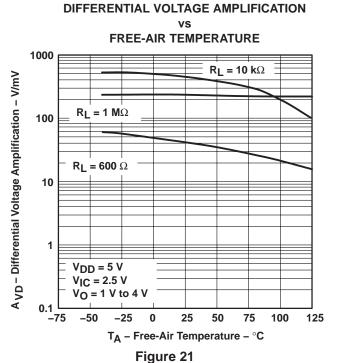


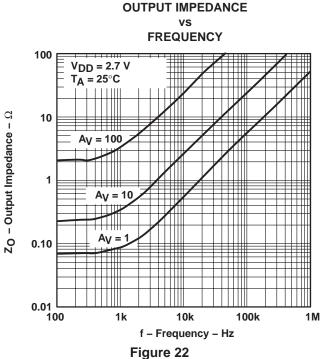


## **DIFFERENTIAL VOLTAGE AMPLIFICATION** LOAD RESISTANCE 250 T<sub>A</sub> = 25°C A<sub>VD</sub> - Differential Voltage Amplification - V/mV 200 $V_{DD} = 2.7 \text{ V}$ $V_{DD} = 5 V$ 150 100 50 0 0.1 10 100 1000 $R_L$ – Load Resistance – $k\Omega$

Figure 19







#### TYPICAL CHARACTERISTICS

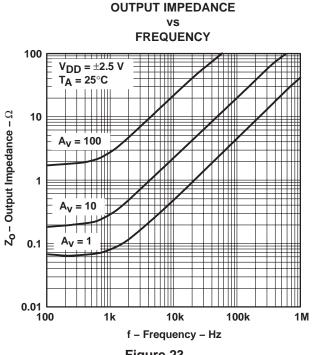


Figure 23

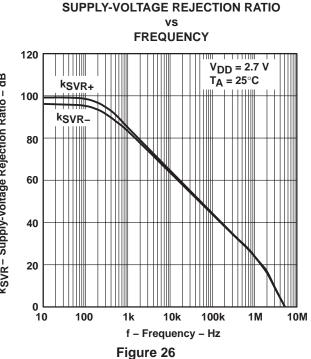
#### **FREQUENCY** V<sub>DD</sub> = 2.7 V 90 $V_{IC} = 1.35 \text{ V}$ CMRR - Common-Mode Rejection Ratio - dB and 2.5 V | | | | | | | | | | | T<sub>A</sub> = 25°C $V_{DD} = 5 V$ 80 70 60 50 40 10 100 1k 10k 100k 1M 10M f - Frequency - Hz

**COMMON-MODE REJECTION RATIO** 

Figure 24

#### **COMMON-MODE REJECTION RATIO** FREE-AIR TEMPERATURE 120 CMRR - Common-Mode Rejection Ratio - dB 115 110 105 100 $V_{DD} = 2.7 \text{ V}$ 95 90 $V_{DD} = 5 V$ 85 80 -40 -20 0 20 40 60 80 100 120 140 $T_A$ – Free-Air Temperature – $^\circ C$ Figure 25

kSVR- Supply-Voltage Rejection Ratio - dB



#### **TYPICAL CHARACTERISTICS**

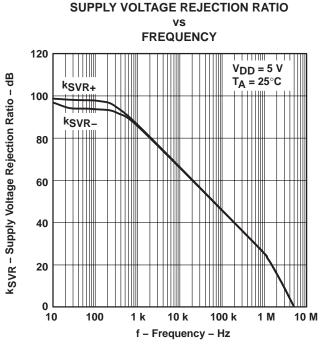
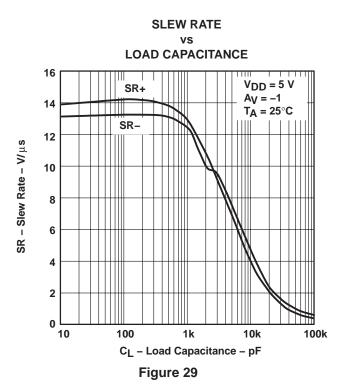
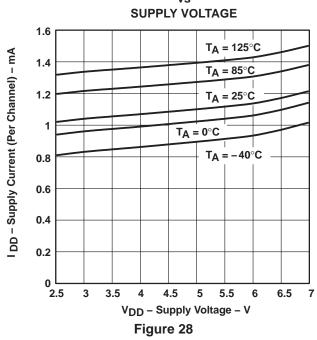


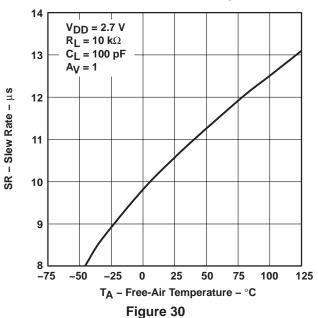
Figure 27



SUPPLY CURRENT (PER CHANNEL)

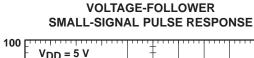


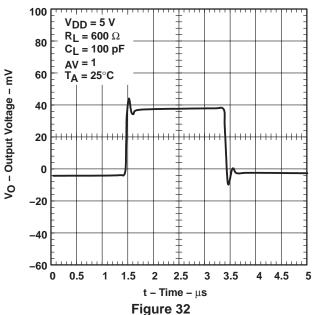
SLEW RATE vs FREE-AIR TEMPERATURE



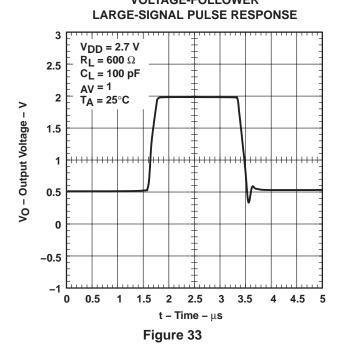
#### **VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE** 100 $V_{DD} = 2.7 V$ $R_L = 600 \Omega$ 80 $C_L = 100 pF$ AV = 1Vo - Output Voltage - mV 60 T<sub>A</sub> = 25°C 40 20 0 -20 -40 -60 2.5 0 0.5 1 1.5 2 3 3.5 4 4.5 t – Time – $\mu$ s

Figure 31

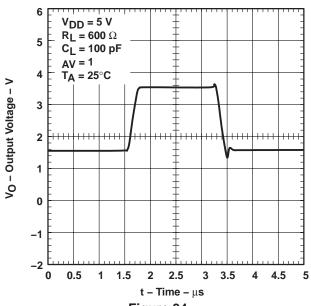


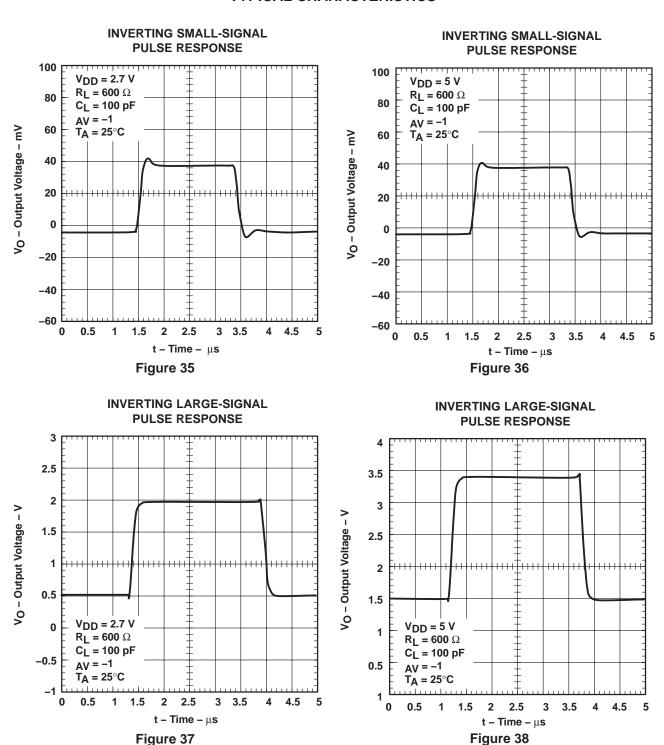


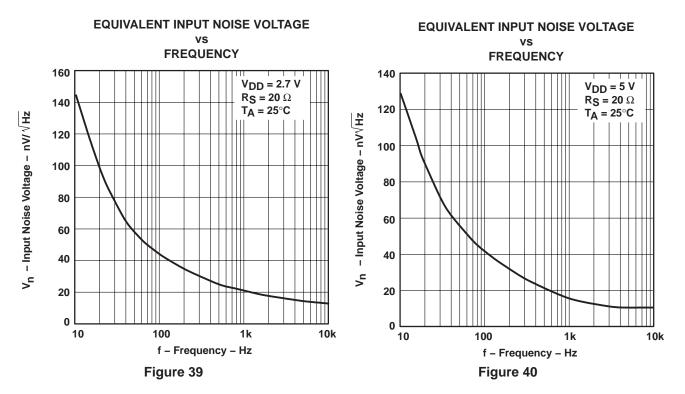
VOLTAGE-FOLLOWER



VOLTAGE-FOLLOWER
LARGE-SIGNAL PULSE RESPONSE







# NOISE VOLTAGE OVER A 10 SECOND PERIOD

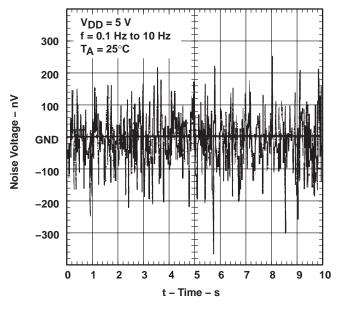


Figure 41

 $V_{DD} = 5 V$ 

 $T_A = 25^{\circ}C$ 

 $R_L = 600 \Omega$ 

 $A_{V} = 100$ 

 $A_{V} = 10$ 

 $A_V = 1$ 

100

TOTAL HARMONIC DISTORTION PLUS NOISE

**FREQUENCY** 

1k

f - Frequency - Hz

**UNITY-GAIN BANDWIDTH** vs

10k

100k

#### TYPICAL CHARACTERISTICS

#### TOTAL HARMONIC DISTORTION PLUS NOISE **FREQUENCY** 10 THD+N - Total Harmonic Distortion Plus Noise - % $V_{DD} = 2.7 V$ $R_L = 600 \Omega$ T<sub>A</sub> = 25°C $A_V = 100$ 0.1 $A_{V} = 10$ $A_V = 1$ 0.01 0.001 10 100 1k 10k 100k



f - Frequency - Hz

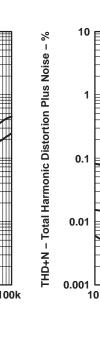
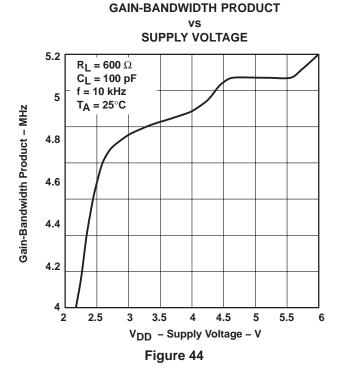
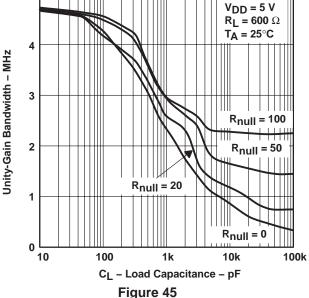
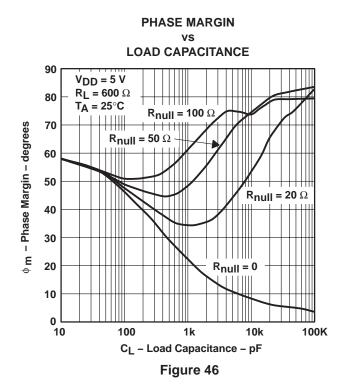


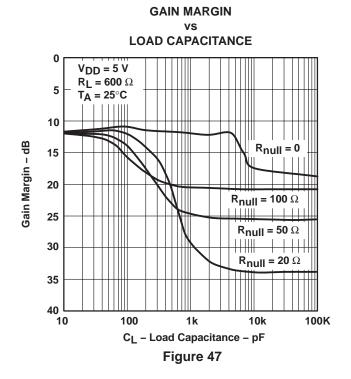
Figure 43

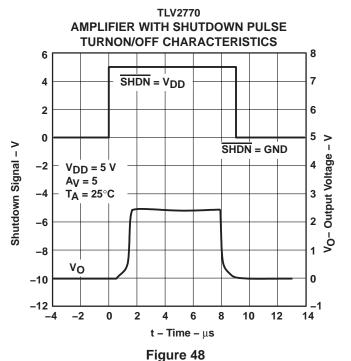


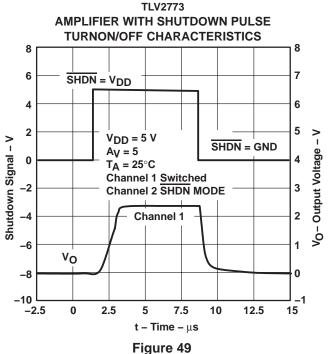
LOAD CAPACITANCE 5 4

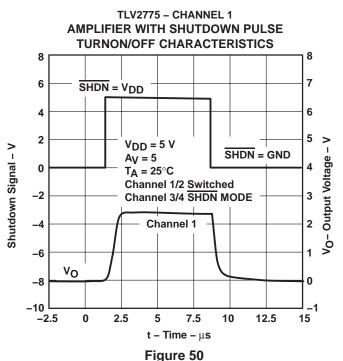






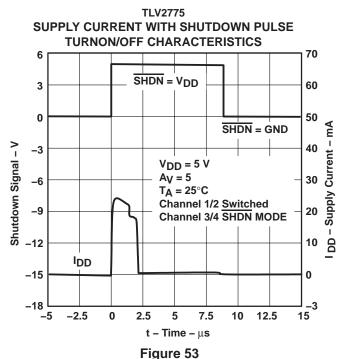




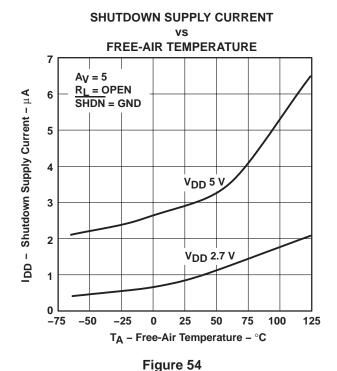


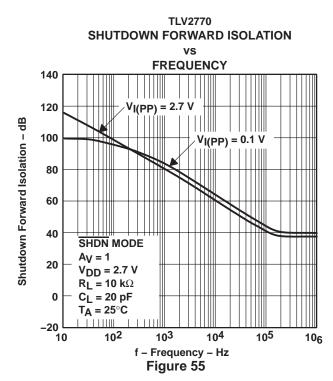
**TLV2770** SUPPLY CURRENT WITH SHUTDOWN PULSE **TURNON/OFF CHARACTERISTICS** 24 SHDN = V<sub>DD</sub> 21 4 18 2 DD - Supply Current - mA 15 0 Shutdown Signal - V SHDN = GND 12 -2  $V_{DD} = 5 V$ 9 -4  $A_V = 5$  $T_A = 25^{\circ}C$ 6 -6 3 -8 IDD 0 -10 -12 -3 0 6 10 -4 -2 12 14 t – Time –  $\mu$ s Figure 51

**TLV2773** SUPPLY CURRENT WITH SHUTDOWN PULSE **TURNON/OFF CHARACTERISTICS** 70 6  $\overline{SHDN} = V_{DD}$ 60 3 0 50 DD - Supply Current - mA SHDN = GND 40  $V_{DD} = 5 V$  $A_V = 5$ 30 T<sub>A</sub> = 25°C Channel 1 Switched 20 Channel 2 SHDN MODE 10 IDD 0 -15-18 -3 -2.5 15 -5 0 2.5 5 7.5 10 12.5 t - Time - μs Figure 52

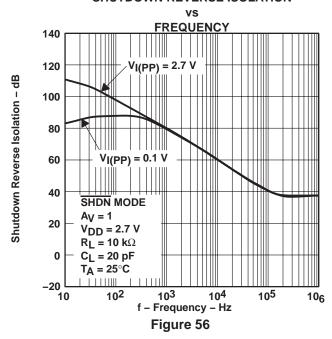


#### TYPICAL CHARACTERISTICS





#### TLV2770 SHUTDOWN REVERSE ISOLATION





#### PARAMETER MEASUREMENT INFORMATION

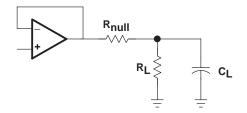


Figure 57

#### driving a capacitive load

When the amplifier is configured in this manner, capacitive loading directly on the output decreases the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series ( $R_{NULL}$ ) with the output of the amplifier, as shown in Figure 58. A minimum value of 20  $\Omega$  should work well for most applications.

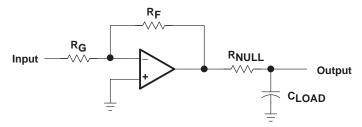


Figure 58. Driving a Capacitive Load

#### APPLICATION INFORMATION

#### offset voltage

The output offset voltage,  $(V_{OO})$  is the sum of the input offset voltage  $(V_{IO})$  and both input bias currents  $(I_{IB})$  times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:

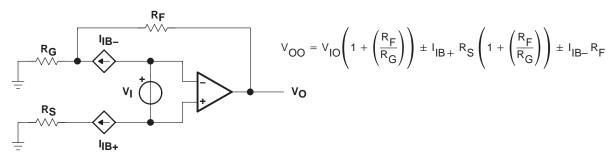


Figure 59. Output Offset Voltage Model

#### general configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 60).

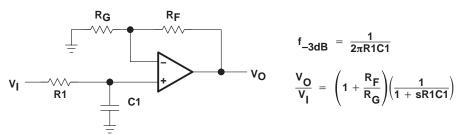


Figure 60. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

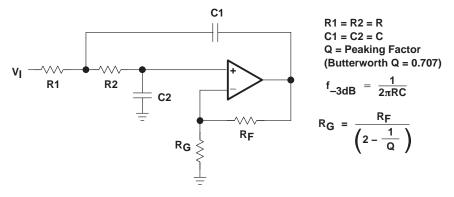


Figure 61. 2-Pole Low-Pass Sallen-Key Filter

#### **APPLICATION INFORMATION**

#### using the TLV2772 as an accelerometer interface

The schematic, shown in Figure 62, shows the ACH04-08-05 interfaced to the TLV1544 10-bit analog-to-digital converter (ADC).

The ACH04-08-05 is a shock sensor designed to convert mechanical acceleration into electrical signals. The sensor contains three piezoelectric sensing elements oriented to simultaneously measure acceleration in three orthogonal, linear axes (x, y, z). The operating frequency is 0.5 Hz to 5 kHz. The output is buffered with an internal JFET and has a typical output voltage of 1.80 mV/g for the x and y axis and 1.35 mV/g for the z axis.

Amplification and frequency shaping of the shock sensor output is done by the TLV2772 rail-to-rail operational amplifier. The TLV2772 is ideal for this application as it offers high input impedance, good slew rate, and excellent dc precision. The rail-to-rail output swing and high output drive are perfect for driving the analog input of the TLV1544 ADC.

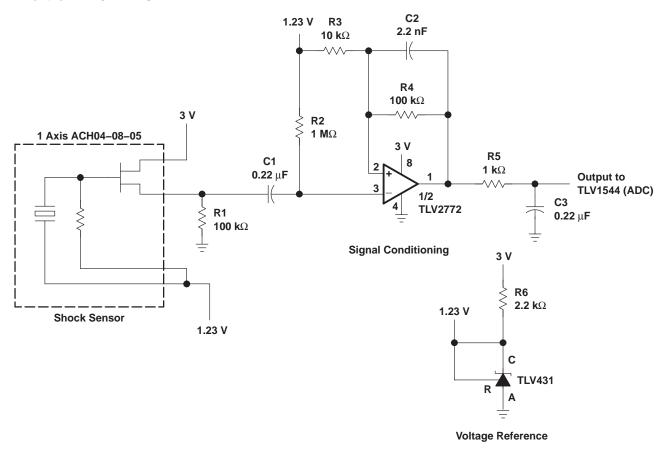


Figure 62. Accelerometer Interface Schematic

The sensor signal must be amplified and frequency-shaped to provide a signal the ADC can properly convert into the digital domain. Figure 62 shows the topology used in this application for one axis of the sensor. This system is powered from a single 3-V supply. Configuring the TLV431 with a 2.2-k $\Omega$  resistor produces a reference voltage of 1.23 V. This voltage is used to bias the operational amplifier and the internal JFETs in the shock sensor.



#### **APPLICATION INFORMATION**

#### gain calculation

Since the TLV2772 is capable of rail-to-rail output using a 3-V supply,  $V_O = 0$  (min) to 3 V (max). With no signal from the sensor, nominal  $V_O =$  reference voltage = 1.23 V. Therefore, the maximum negative swing from nominal is 0 V - 1.23 V = -1.23 V and the maximum positive swing is 3 V - 1.23 V = 1.77 V. By modeling the shock sensor as a low impedance voltage source with output of 2.25 mV/g (max) in the x and y axis and 1.7 mV/g (max) in the z axis, the gain of the circuit is calculated by equation 1.

$$Gain = \frac{Output Swing}{Sensor Signal \times Acceleration}$$
 (1)

To avoid saturation of the operational amplifier, the gain calculations are based on the maximum negative swing of –1.23 V and the maximum sensor output of 2.25 mV/g (x and y axis) and 1.70 mV/g (z axis).

Gain (x, y) = 
$$\frac{-1.23 \text{ V}}{2.25 \text{ mV/g} \times -50 \text{ g}} = 10.9$$
 (2)

and

Gain (z) = 
$$\frac{-1.23 \text{ V}}{1.70 \text{ mV/g} \times -50 \text{ g}}$$
 = 14.5 (3)

By selecting R3 = 10 k $\Omega$  and R4 = 100 k $\Omega$ , in the x and y channels, a gain of 11 is realized. By selecting R3 = 7.5 k $\Omega$  and R4 = 100 k $\Omega$ , in the z channel, a gain of 14.3 is realized. The schematic shows the configuration for either the x- or y-axis.

#### bandwidth calculation

To calculate the component values for the frequency shaping characteristics of the signal conditioning circuit, 1 Hz and 500 Hz are selected as the minimum required 3-dB bandwidth.

To minimize the value of the input capacitor (C1) required to set the lower cutoff frequency requires a large value resistor for R2 is required. A 1-M $\Omega$  resistor is used in this example. To set the lower cutoff frequency, the required capacitor value for C1 is:

$$C1 = \frac{1}{2\pi f_{LOW} R_2} = 0.159 \,\mu\text{F} \tag{4}$$

Using a value of 0.22 μF, a more common value of capacitor, the lower cutoff frequency is 0.724 Hz.

To minimize the phase shift in the feedback loop caused by the input capacitance of the TLV2772, it is best to minimize the value of the feedback resistor R4. However, to reduce the required capacitance in the feedback loop a large value for R4 is required. Therefore, a compromise for the value of R4 must be made. In this circuit, a value of  $100 \text{ k}\Omega$  has been selected. To set the upper cutoff frequency, the required capacitor value for C2 is:

$$C2 = \frac{1}{2\pi f_{HIGH} R_4} = 3.18 \,\mu\text{F} \tag{5}$$

Using a 2.2-nF capacitor, the upper cutoff frequency is 724 Hz.

R5 and C3 also cause the signal response to roll off. Therefore, it is beneficial to design this roll-off point to begin at the upper cutoff frequency. Assuming a value of 1 k $\Omega$  for R5, the value for C3 is calculated to be 0.22  $\mu$ F.



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#### APPLICATION INFORMATION

#### circuit layout considerations

To achieve the levels of high performance of the TLV277x, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

- Ground planes—It is highly recommended that a ground plane be used on the board to provide all
  components with a low inductive ground connection. However, in the areas of the amplifier inputs and
  output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling—Use a 6.8-μF tantalum capacitor in parallel with a 0.1-μF ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1-μF ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1-μF capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets—Sockets can be used but are not recommended. The additional lead inductance in the socket pins
  will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board
  is the best implementation.
- Short trace runs/compact part placements—Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This helps to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components—Using surface-mount passive components is recommended for high
  performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of
  surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small
  size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray
  inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be
  kept as short as possible.



#### APPLICATION INFORMATION

#### general power dissipation considerations

For a given  $\theta_{JA}$ , the maximum power dissipation is shown in Figure 63 and is calculated by the following formula:

$$P_{D} = \left(\frac{T_{MAX}^{-T}A}{\theta_{JA}}\right)$$

Where:

P<sub>D</sub> = Maximum power dissipation of TLV277x IC (watts)

T<sub>MAX</sub> = Absolute maximum junction temperature (150°C)

 $T_A$  = Free-ambient air temperature (°C)

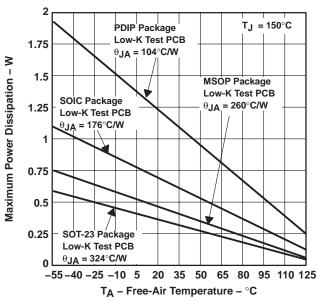
 $\theta_{JA} = \theta_{JC} + \theta_{CA}$ 

 $\theta_{JC}$  = Thermal coefficient from junction-to-case

 $\theta_{CA}$  = Thermal coefficient from case to ambient air (°C/W)

#### **MAXIMUM POWER DISSIPATION**

#### vs FREE-AIR TEMPERATURE



NOTE A: Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 63.

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#### **APPLICATION INFORMATION**

#### shutdown function

Three members of the TLV277x family (TLV2770/3/5) have a shutdown terminal for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 0.8  $\mu$ A/channel, the amplifier is disabled, and the outputs are placed in a high impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, care needs to be taken to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown. The shutdown terminal threshold is always referenced to  $V_{DD}/2$ . Therefore, when operating the device with split supply voltages (e.g.  $\pm 2.5$  V), the shutdown terminal needs to be pulled to  $V_{DD}$ – (not GND) to disable the operational amplifier.

The amplifier's output with a shutdown pulse is shown in Figure 48 through Figure 50. The amplifier is powered with a single 5-V supply and configured as a noninverting configuration with a gain of 5. The amplifier turnon and turnoff times are measured from the 50% point of the shutdown pulse to the 50% point of the output waveform. The times for the single, dual, and quad are listed in the data tables. The *bump* on the rising edge of the TLV2770 output waveform is due to the start-up circuit on the bias generator. For the dual and quad (TLV2773/5), this *bump* is attributed to the bias generator's start-up circuit as well as the crosstalk between the other channel(s), which are in shutdown.

Figure 55 and Figure 56 show the amplifier's forward and reverse isolation in shutdown. The operational amplifier is powered by  $\pm 1.35$ -V supplies and configured as a voltage follower ( $A_V = 1$ ). The isolation performance is plotted across frequency for both 0.1-V<sub>PP</sub> and 2.7-V<sub>PP</sub> input signals. During normal operation, the amplifier would not be able to handle a 2.7-V<sub>PP</sub> input signal with a supply voltage of  $\pm 1.35$  V since it exceeds the common-mode input voltage range ( $V_{ICR}$ ). However, this curve illustrates that the amplifier remains in shutdown even under a worst case scenario.



#### APPLICATION INFORMATION

#### macromodel information

Macromodel information provided was derived using Microsim  $Parts^{TM}$  Release 8, the model generation software used with Microsim  $PSpice^{TM}$ . The Boyle macromodel (see Note 4) and subcircuit in Figure 64 are generated using the TLV2772 typical electrical and operating characteristics at  $T_A = 25^{\circ}C$ . Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification

- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 5: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

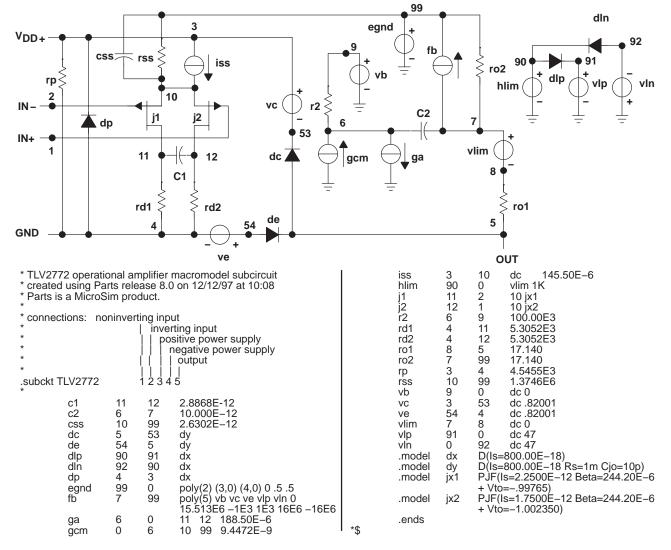


Figure 64. Boyle Macromodel and Subcircuit

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#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TLV2771QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV2772AQDRQ1	ACTIVE	SOIC	D	8	2500	TBD	Call TI	Call TI
TLV2772AQPWRQ1	ACTIVE	TSSOP	PW	8	2000	TBD	Call TI	Call TI
TLV2772QDRQ1	ACTIVE	SOIC	D	8	2500	TBD	Call TI	Call TI
TLV2772QPWRQ1	ACTIVE	TSSOP	PW	8	2000	TBD	CU NIPDAU	Level-1-220C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

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Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

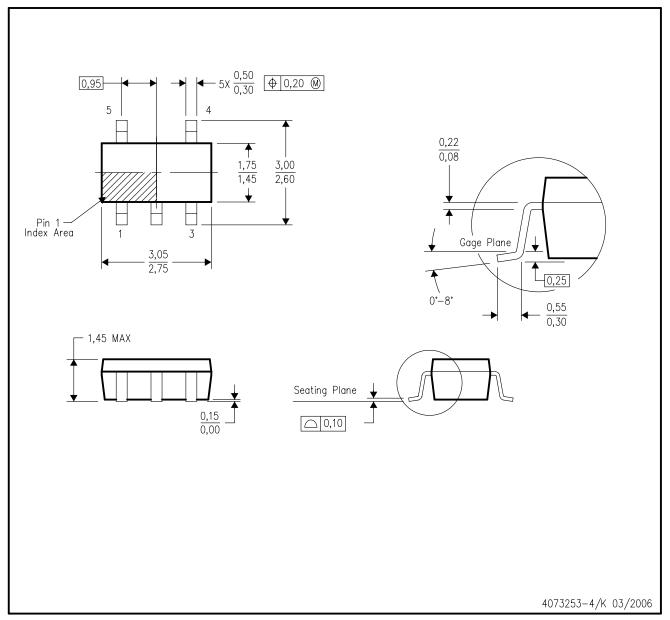
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# DBV (R-PDSO-G5)

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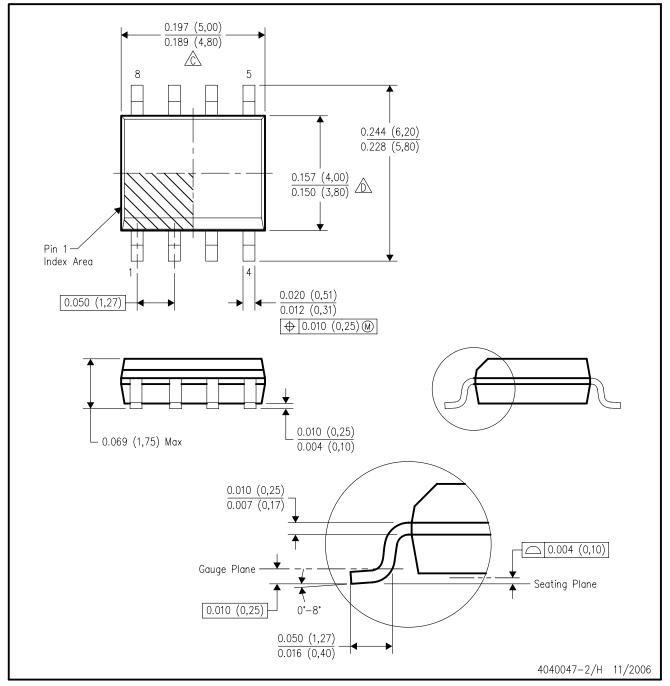
NOTES:

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  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-178 Variation AA.



## D (R-PDSO-G8)

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NOTES:

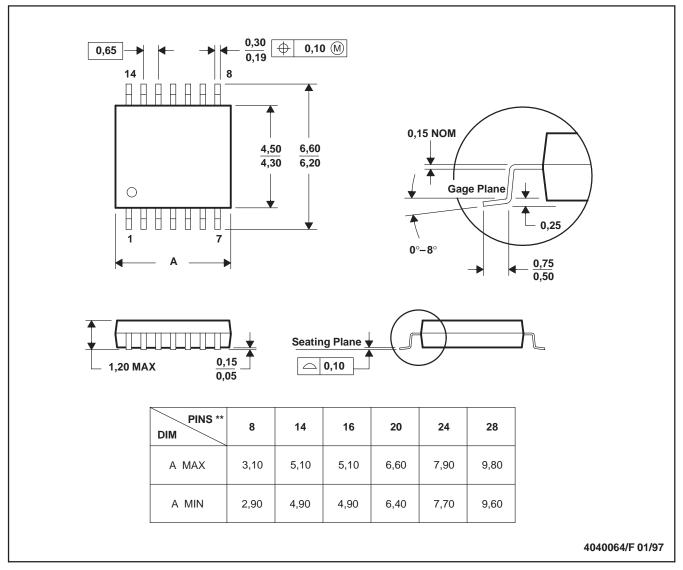
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AA.



#### PW (R-PDSO-G\*\*)

#### 14 PINS SHOWN

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